Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier



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PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V _{RRM}	90 V, 100 V			
I _{FSM}	150 A			
V_F at $I_F = 10$ A	0.65 V			
T _J max.	150 °C			
Package	ITO-220AB			
Diode variation	Dual common cathode			

FEATURES

- Trench MOS Schottky technology
- Low power losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- High frequency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_C = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	MBRF2090CT	MBRF20100CT	UNIT
Maximum repetitive peak reverse voltage		V _{RRM}	90	100	V
Working peak reverse voltage		V _{RWM}	90	100	V
Maximum DC blocking voltage		V _{DC}	90	100	V
Maximum average forward rectified current at T_C = 133 $^\circ\text{C}$	total device	leure.	20		A
	per diode	I _{F(AV)}	10		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	150		А
Voltage rating of change (rated V _R)		dV/dt	10 000		V/µs
Operating junction and storage temperature range		T _J , T _{STG}	-65 to +150		°C
Isolation voltage from terminal to heatsink t = 1 min		V _{AC}	1500		V



FREE



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ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage per diode	I _F = 10 A	T _C = 25 °C	VF ⁽¹⁾	0.80	V
		T _C = 125 °C		0.65	
	I _F = 20 A			0.75	
Maximum reverse current per diode at working peak reverse voltage		$T_J = 25 \ ^{\circ}C$	B (2)	100	μA
		T _J = 100 °C		6.0	mA

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_c = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	MBRF	UNIT	
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	3.5	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N UNIT WEIGHT (g) PACKAGE CO		PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AB	MBRF20100CT-M3/4W	1.75	4W	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

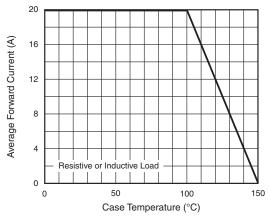


Fig. 1 - Forward Current Derating Curve

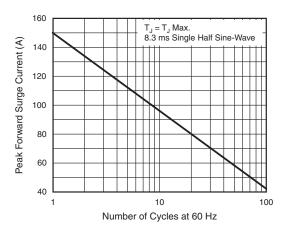


Fig. 2 - Maximum Non-Repetititve Peak Forward Surge Current Per Diode



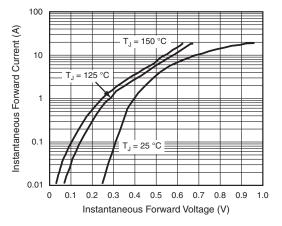


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

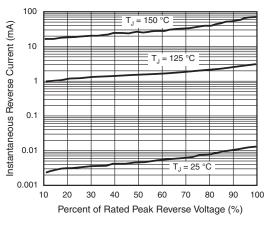


Fig. 4 - Typical Reverse Characteristics Per Diode



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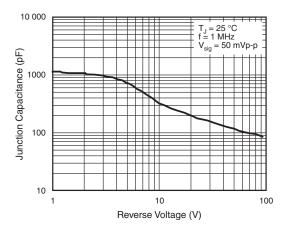


Fig. 5 - Typical Junction Capacitanc Per Diode

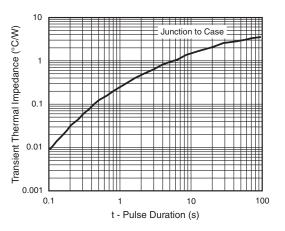
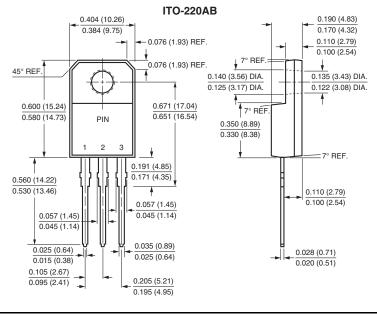


Fig. 6 - Typical Transient Thermal Impedance Per Diode



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

 Revision: 17-Aug-15
 3
 Document Number: 89319

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